



19TQ015S SCHOTTKY RECTIFIER

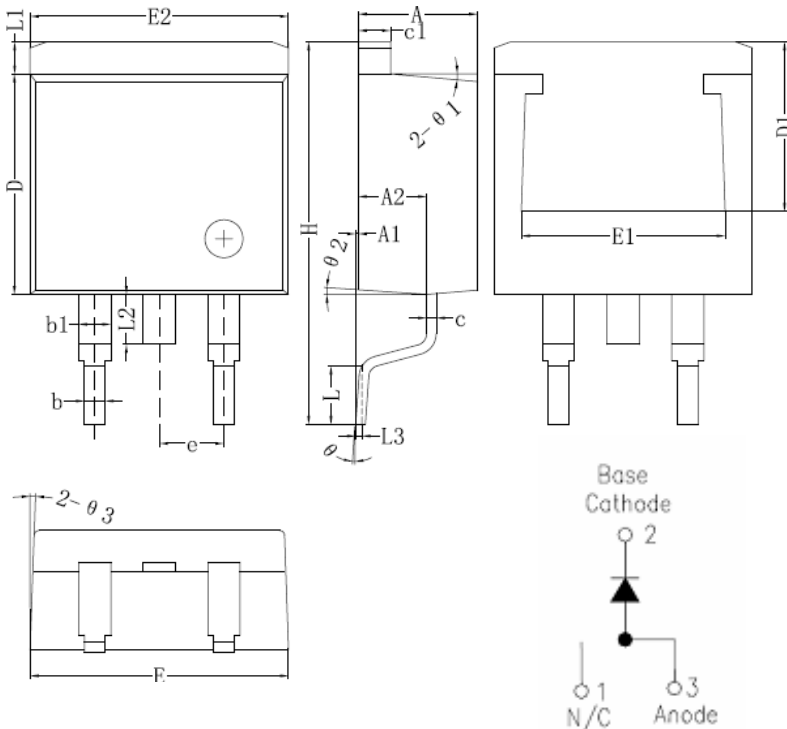
Applications:

- Switching power supply
- Redundant power subsystems
- Converters
- Free-Wheeling diodes
- Reverse battery protection

Features:

- 100°C T_J operation
- High purity, high temperature epoxy encapsulation for enhanced mechanical strength and moisture resistance
- Low forward voltage drop
- High frequency operation
- Guard ring for enhanced ruggedness and long term reliability
- This is a Pb – Free Device
- All SMC parts are traceable to the wafer lot
- Additional testing can be offered upon request

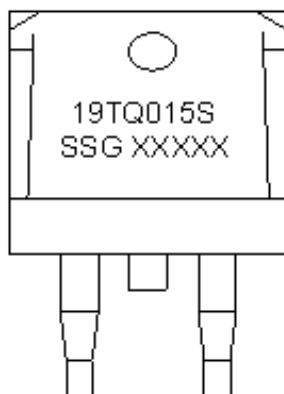
Mechanical Dimensions: In Inches / mm



| Symbol | Dimensions in millimeters | | |
|--------|---------------------------|---------|-------|
| | Min. | Typical | Max. |
| A | 4.55 | 4.70 | 4.85 |
| A1 | 0 | 0.10 | 0.25 |
| A2 | 2.59 | 2.69 | 2.89 |
| b | 0.71 | 0.81 | 0.96 |
| b1 | | 1.27 | |
| c | 0.36 | 0.38 | 0.61 |
| c1 | 1.17 | 1.27 | 1.37 |
| D | 8.55 | 8.70 | 8.85 |
| D1 | 6.40 | | |
| E | 10.01 | 10.16 | 10.31 |
| E1 | 7.6 | | |
| E2 | 9.98 | 10.08 | 10.18 |
| e | | 2.54 | |
| H | 14.6 | 15.1 | 15.6 |
| L | 2.00 | 2.30 | 2.70 |
| L1 | 1.17 | 1.27 | 1.40 |
| L2 | | | 2.20 |
| L3 | | 0.25BSC | |
| e | 0 | - | 8° |
| e1 | | 5° | |
| e2 | | 4° | |
| e3 | | 4° | |

D²PAK

Marking Diagram:



Where XXXXX is YYWWL

19TQ015S = Part Name
SSG = SSG
YY = Year
WW = Week
L = Lot Number

Cautions: Molding resin
Epoxy resin UL:94V-0

Ordering Information:

| Device | Package | Shipping |
|----------|---------------------------------|---------------|
| 19TQ015S | D ² PAK (Pb-Free) | 800pcs / reel |

For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specification.

Maximum Ratings:

| Characteristics | Symbol | Condition | Max. | Units |
|---|-------------|--|------|-------|
| Peak Inverse Voltage | V_{RWM} | - | 15 | V |
| Average Forward Current | $I_{F(AV)}$ | 50% duty cycle @ $T_C = 75^\circ\text{C}$, rectangular wave form | 19 | A |
| Peak One Cycle Non-Repetitive Surge Current (per leg) | I_{FSM} | 8.3 ms, half Sine pulse | 120 | A |



Electrical Characteristics:

| Characteristics | Symbol | Condition | Max. | Units |
|--------------------------------|----------|---|--------------|------------------|
| Forward Voltage Drop | V_{F1} | @ 19A, Pulse, $T_A = 25\text{ }^\circ\text{C}$ @ 38A, Pulse, $T_A = 25\text{ }^\circ\text{C}$ | 0.36 0.46 | V |
| Reverse Current (per leg) * | I_{R1} | @ $V_R = \text{rated } V_R$ $T_J = 25\text{ }^\circ\text{C}$ | 10.5 | mA |
| Junction Capacitance (per leg) | C_T | @ $V_R = 5\text{V}$, $T_C = 25\text{ }^\circ\text{C}$ $f_{SIG} = 100\text{KHz} - 1\text{MHz}$ | 2500 | pF |
| Voltage Rate of Change | dv/dt | - | 10,000 | V/ μs |

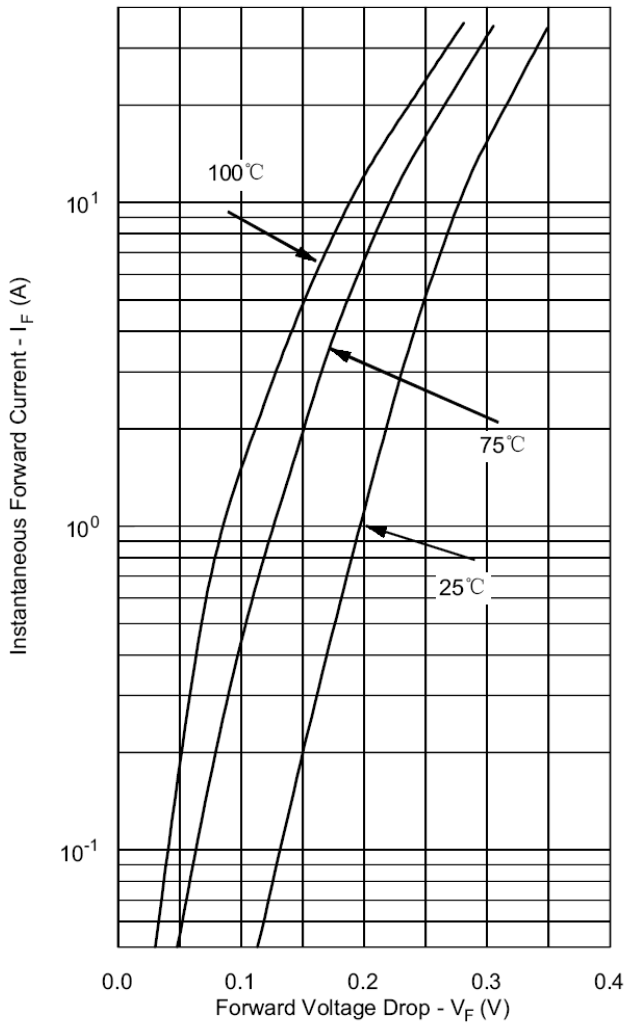
* Pulse Width < 300 μs , Duty Cycle <2%

Thermal-Mechanical Specifications:

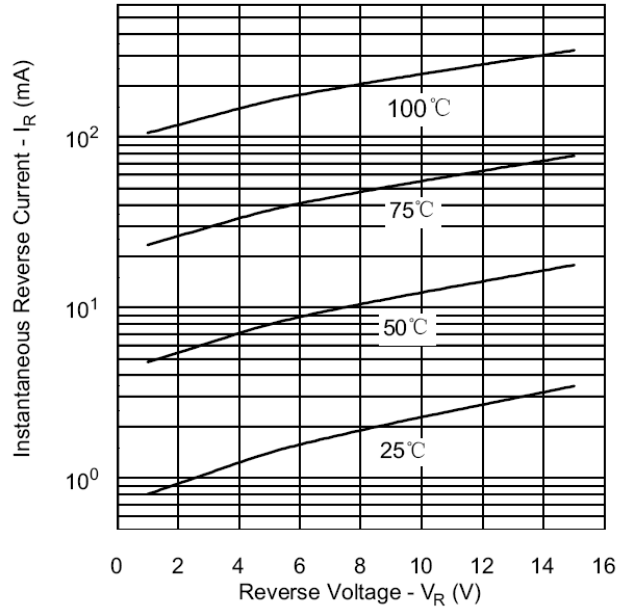
| Characteristics | Symbol | Condition | Specification | Units |
|---|-----------------|--------------|---------------|--------------------|
| Junction Temperature | T_J | - | -55 to +100 | $^\circ\text{C}$ |
| Storage Temperature | T_{stg} | - | -55 to +100 | $^\circ\text{C}$ |
| Maximum Thermal Resistance Junction to Case (per package) | $R_{\theta JC}$ | DC operation | 0.8 | $^\circ\text{C/W}$ |
| Approximate Weight | wt | - | 2 | g |
| Case Style | D2PAK | | | |



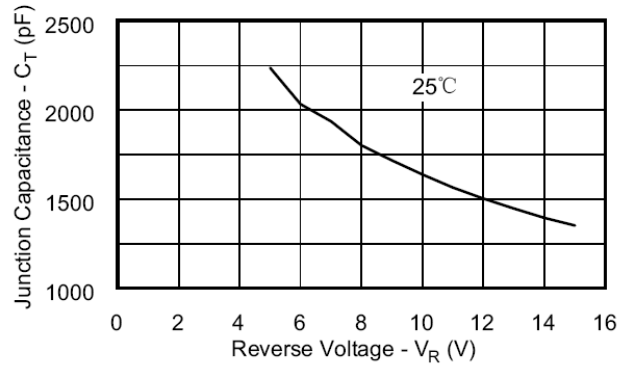
Typical Forward Characteristics



Typical Reverse Characteristics



Typical Junction Capacitance





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